

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor TK10A50W, ITK10A50W

FEATURES

- Low drain-source on-resistance: RDs(ON) = 0.38Ω
- · Easy to control Gate switching
- Enhancement mode: Vth = 2.7 to 3.7 V (VDs = 10 V, ID=0.5 mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

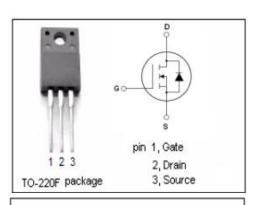
Switching Voltage Regulators

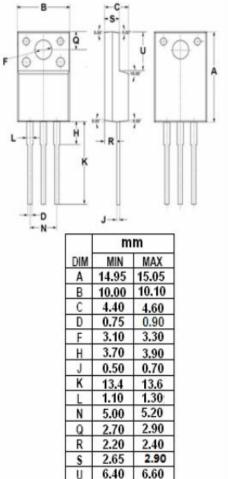
• ABSOLUTE MAXIMUM RATINGS(Ta=25 C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V _{DSS}	Drain-Source Voltage	500	V			
V _{GS}	Gate-Source Voltage	±30	V			
ID	Drain Current-Continuous	9.7	А			
I _{DM}	Drain Current-Single Pulsed	38.8	A			
PD	Total Dissipation @T _c =25°C	30	W			
Tj	Max. Operating Junction Temperature	150	°C			
T _{stg}	Storage Temperature	-55~150	°C			

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	4.17	°C/W
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C/W





isc website: www.iscsemi.cn

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ELECTRICAL CHARACTERISTICS

 $T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	500			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D = 0.5mA	2.7		3.7	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 4.9A			380	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 500V; V _{GS} = 0V			10	μA
V _{SDF}	Diode forward voltage	I _{DR} = 9.7 A, V _{GS} = 0 V			1.7	V

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